

# NUF6401MN

## Advance Information EMI Filter with ESD Protection

This device is an 6 line EMI filter array for wireless applications. Greater than -35 dB attenuation is obtained at frequencies from 800 MHz to 2.4 GHz. It also offers ESD protection—clamping transients from static discharges. ESD protection is provided across all capacitors.

### Features

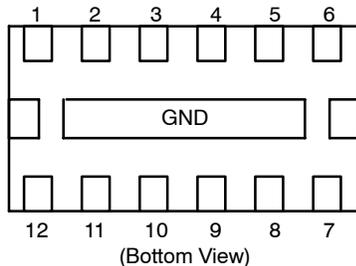
- EMI Filtering and ESD Protection
- Integration of 30 Discrete Components
- Compliance with IEC61000-4-2 (Level 4)  
> 8.0 kV (Contact)
- DFN Package, 1.35 x 3.0 mm
- Moisture Sensitivity Level 1
- ESD Ratings: Machine Model = C  
Human Body Model = 3B
- This is a Pb-Free Device\*

### Benefits

- Reduces EMI/RFI Emissions on a Data Line
- Integrated Solution Offers Cost and Space Savings in a DFN Package
- Reduces Parasitic Inductances Which Offer a More “Ideal” Low Pass Filter Response
- Integrated Solution Improves System Reliability
- Compatible Footprint to BGA or Flip-Chip Package

### Applications

- EMI Filtering and ESD Protection for Data Lines
- Wireless Phones
- PDAs and Handheld Products
- Notebook Computers
- LCD Displays



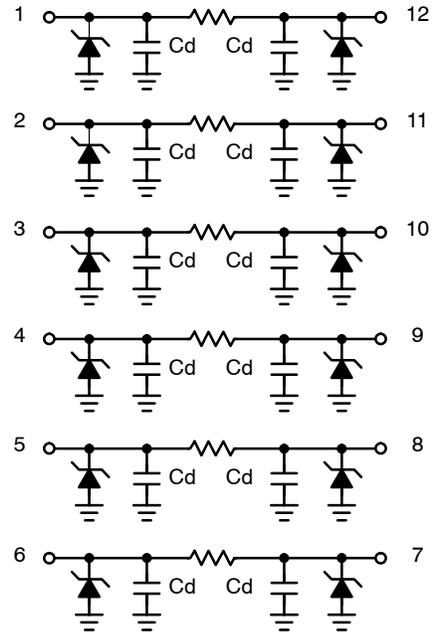
\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

This document contains information on a new product. Specifications and information herein are subject to change without notice.

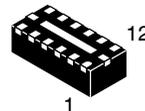


ON Semiconductor®

<http://onsemi.com>



(Top View)



DFN12  
CASE 506AD

### MARKING DIAGRAM

6401 D

6401 = Specific Device Code  
D = Date Code

### ORDERING INFORMATION

Device	Package	Shipping†
NUF6401MNT1G	DFN	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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## MAXIMUM RATINGS (T<sub>J</sub> = 25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
ESD Discharge IEC61000-4-2 Air Discharge Contact Discharge	V <sub>PP</sub>	15 8.0	kV
Steady-State Power per Resistor	P <sub>R</sub>		mW
Steady-State Power per Package	P <sub>T</sub>		mW
Operating Temperature Range	T <sub>OP</sub>	-40 to 85	°C
Storage Temperature Range	T <sub>STG</sub>	-55 to 150	°C
Maximum Lead Temperature for Soldering Purposes (1.8 in from case for 10 seconds)	T <sub>L</sub>	260	°C

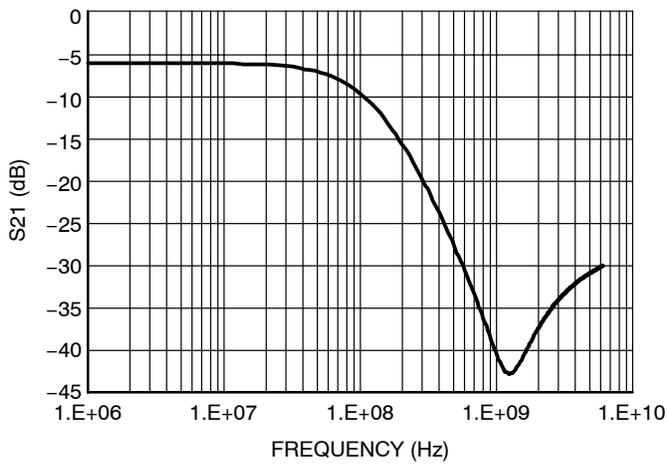
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

## ELECTRICAL CHARACTERISTICS (T<sub>J</sub> = 25°C unless otherwise noted)

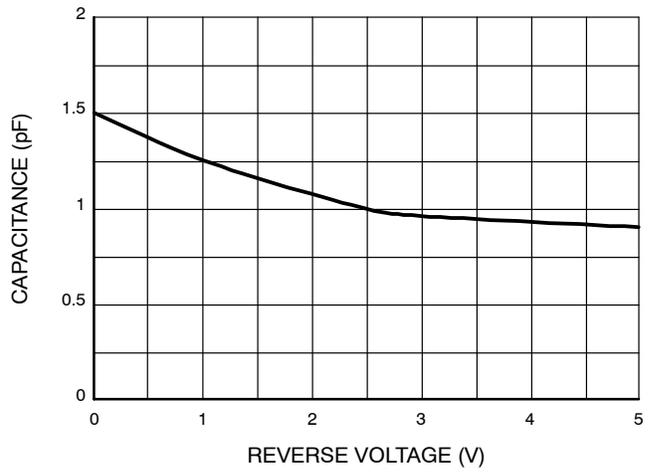
Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Maximum Reverse Working Voltage	V <sub>RWM</sub>				5.0	V
Breakdown Voltage	V <sub>BR</sub>	I <sub>R</sub> = 1.0 mA	6.0	7.0		V
Leakage Current	I <sub>R</sub>	V <sub>RWM</sub> = 3.0 V			1.0	μA
Resistance	R <sub>A</sub>	I <sub>R</sub> = 20 mA	85	100	115	Ω
Capacitance (Notes 1 and 2)	C <sub>d</sub>	V <sub>R</sub> = 2.5 V, f = 1.0 MHz		20		pF
Cut-Off Frequency (Note 3)	f <sub>3dB</sub>	Above this frequency, appreciable attenuation occurs		95		MHz

1. Measured at 25°C, V<sub>R</sub> = 2.5 V, f = 1.0 MHz.
2. Total line capacitance is 2 times the Diode Capacitance (C<sub>d</sub>).
3. 50 Ω source and 50 Ω load termination.

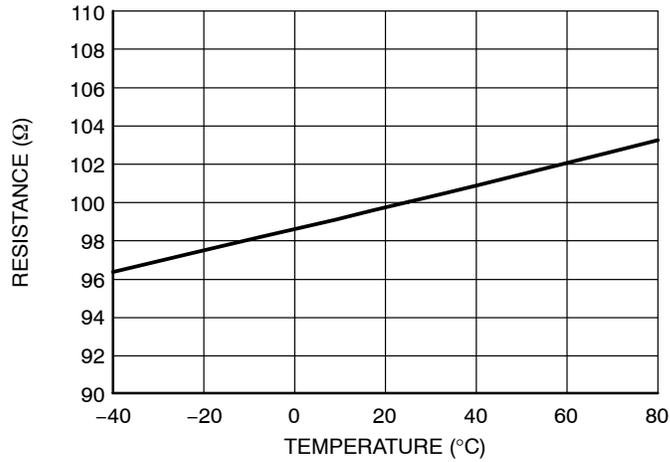
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**Figure 1. Insertion Loss Characteristic (Simulation)**



**Figure 2. Typical Capacitance vs. Reverse Biased Voltage (Normalized Capacitance, Cd @ 2.5 V)**

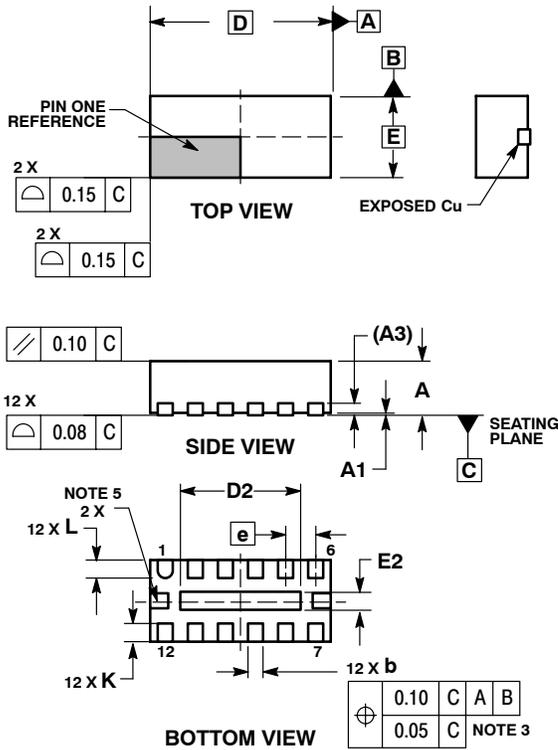


**Figure 3. Typical Resistance over Temperature**

# NUF6401MN

## PACKAGE DIMENSIONS

DFN12  
CASE 506AD-01  
ISSUE O



### NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION b APPLIES TO TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30 MM FROM TERMINAL.
4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.
5. EXPOSED PADS CONNECTED TO DIE FLAG. USED AS TEST CONTACTS.

DIM	MILLIMETERS	
	MIN	MAX
A	0.80	1.00
A1	0.00	0.05
A3	0.20	REF
b	0.18	0.30
D	3.00	BSC
D2	1.90	2.10
E	1.35	BSC
E2	0.20	0.40
e	0.50	BSC
K	0.20	---
L	0.20	0.40

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